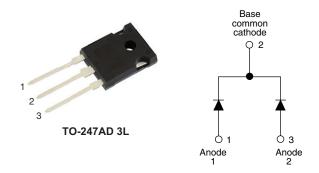


## Ultrafast Soft Recovery Diode, 2 x 30 A FRED Pt® Gen 4



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 30 A				
$V_{R}$	600 V				
V <sub>F</sub> at I <sub>F</sub>	1.19 V				
t <sub>rr</sub> typ.	See Recovery table				
T <sub>J</sub> max.	175 °C				
Package	TO-247AD 3L				
Circuit configuration	Common cathode				

### **FEATURES**

- Gen 4 FRED Pt® technology
- Low I<sub>RRM</sub> and reverse recovery charge
- · Very low forward voltage drop
- Polyimide passivated chip for high reliability standard



- 175 °C operating junction temperature
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### **DESCRIPTION**

Gen 4 Fred technology, state of the art, ultralow  $V_F$ , soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Peak repetitive reverse voltage	$V_{RRM}$		600	V			
Average rectified forward current	I <sub>F(AV)</sub>	TC = 131 °C	30	۸			
Non-repetitive peak surge current, per leg	I <sub>FSM</sub>	$T_C = 25$ °C, $t_p = 8.3$ ms, half sine wave	240	А			
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-		
Forward voltage		I <sub>F</sub> = 30 A	-	1.36	1.6		
		I <sub>F</sub> = 60 A	-	1.6	-	V	
	.,,	I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	1.23	-		
	V <sub>F</sub>	I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C	-	1.5	-		
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.19	1.35		
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 150 °C	-	1.48	-		
Deverse legizone everent		V <sub>R</sub> = V <sub>R</sub> rated	-	-	50		
Reverse leakage current	I <sub>R</sub>	T <sub>J</sub> = 125 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-	500	μA	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	18.3	-	pF	



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL TEST CONDITIONS MIN. TYP. MAX.						UNITS	
Payarea raceyony timo	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 1000 A/μs V <sub>R</sub> = 400 V	-	65	-	ns	
Reverse recovery time		T <sub>J</sub> = 125 °C		-	90	-		
Daali waaasaa aa	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	18	-	A	
Peak recovery current		T <sub>J</sub> = 125 °C		-	32	-		
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	850	-	nC	
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1850	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	1			
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	°C/W		
Thermal resistance, case to heat sink	R <sub>thCS</sub>		-	0.4	-			
Weight			-	6.0	-	g		
weignt			-	0.21	-	oz.		
Mounting torque			6.0 (5)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style TO-247AD 3L	C4PU3006L			•		

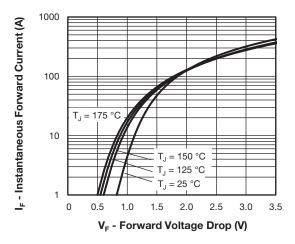


Fig. 1 - Typical Forward Voltage Drop Characteristics

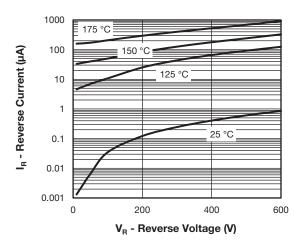


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

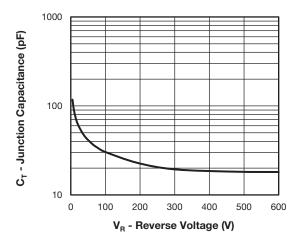


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

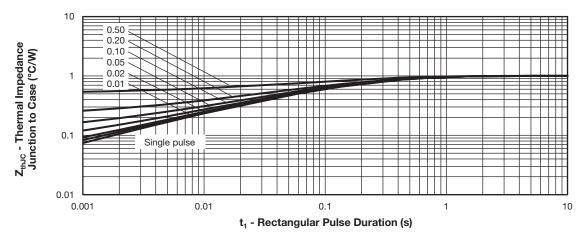


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

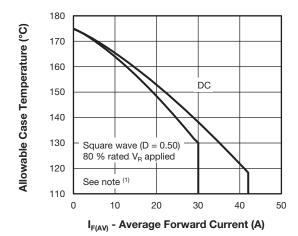


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

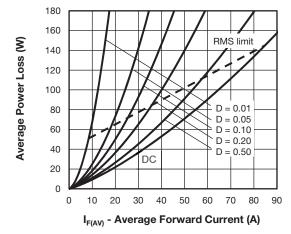


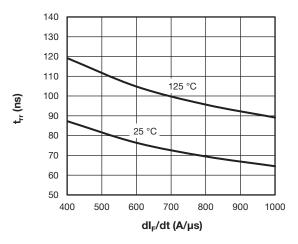
Fig. 6 - Forward Power Loss Characteristics

### Note

<sup>(1)</sup> Formula used: T<sub>C</sub> = T<sub>J</sub> - (P<sub>d</sub> + P<sub>dREV</sub>) x R<sub>thJC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see Fig.5) P<sub>dREV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R</sub> = rated V<sub>R</sub>

### www.vishay.com

# Vishay Semiconductors



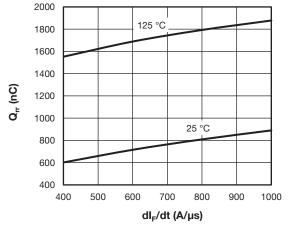


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

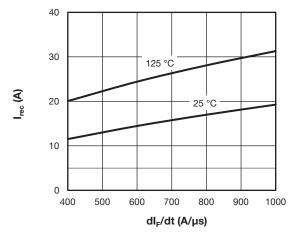
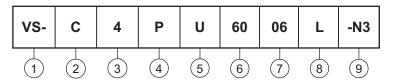


Fig. 9 - Typical Reverse Current vs. dl<sub>F</sub>/dt



### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Circuit configuration:

C = common diode

3 - FRED Pt Gen 4

P = TO-247 package

5 - Process type:

U = ultrafast recovery

6 - Current rating (60 = 2 x 30 A)

7 - Voltage rating (06 = 600 V)

8 - Package: L = long lead

9 - Environmental digit:

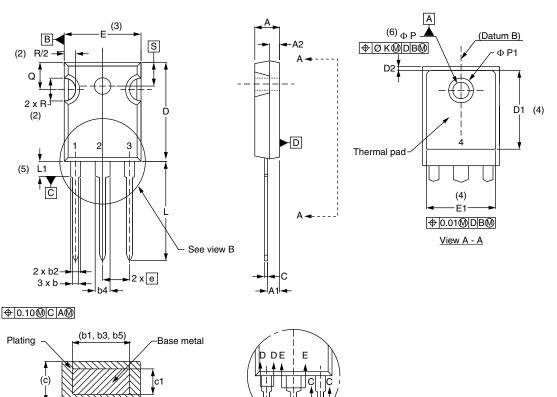
-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-C4PU6006L-N3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95626</u>					
Part marking information	www.vishay.com/doc?95007				

### **TO-247AD 3L**

### **DIMENSIONS** in millimeters and inches



View B

SYMBOL	MILLIMETERS		INC	NOTES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
О	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

Section C - C, D - D, E - E

SYMBOL	MILLIM	IETERS	INC	NOTES	
OTIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215 BSC		
ØK	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	ı	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		
•	•			•	

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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